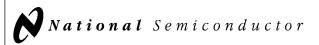
# 54F410,74F410

54F410 74F410 Register Stack-16 x 4 RAM TRI-STATE(RM) Output Register



Literature Number: SNOS197A



# 54F/74F410 Register Stack—16 x 4 RAM TRI-STATE® Output Register

#### **General Description**

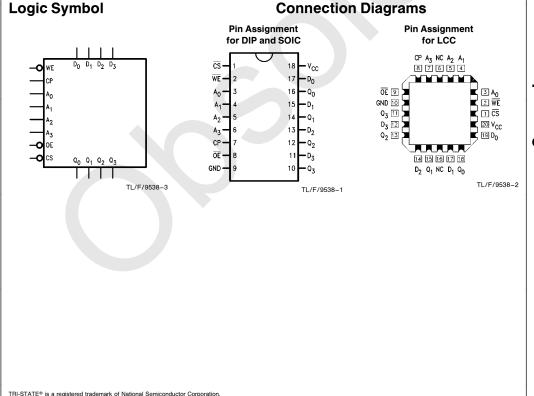
The 'F410 is a register-oriented high-speed 64-bit Read/ Write Memory organized as 16-words by 4-bits. An edgetriggered 4-bit output register allows new input data to be written while previous data is held. TRI-STATE outputs are provided for maximum versatility. The 'F410 is fully compatible with all TTL families.

#### Features

- Edge-triggered output register
- Typical access time of 35 ns
- TRI-STATE outputs
- Optimized for register stack operation
- 18-pin package
- 9410 replacement

Commercial	Military	Package Number	Package Description				
74F410PC		N18A	18-Lead (0.300" Wide) Molded Dual-In-Line				
	54F410DM (Note 1)	J18A	18-Lead Ceramic Dual-In-Line				
74F410SC		M20B	20-Lead (0.300" Wide) Molded Small Outline, JEDEC				
54F410LM		W20A	20-Lead Cerpak				

Note 1: Military grade device with environmental and burn-in processing. Use suffix = DMQB, LMQB



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54F/74F410 Register Stack—16 x 4 RAM TRI-STATE Output Register

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# Unit Loading/Fan Out

		54F/74F			
Pin Names	Description	U.L. HIGH/LOW	Input I <sub>IH</sub> /I <sub>IL</sub> Output I <sub>OH</sub> /I <sub>OL</sub>		
$A_0 - A_3$	Address Inputs	1.0/1.0	20 µA/ −0.6 mA		
$D_0 - D_3$	Data Inputs	1.0/1.0	20 µA/ −0.6 mA		
CS	Chip Select Input (Active LOW)	1.0/2.0	20 μA/ −1.2 mA		
OE	Output Enable Input (Active LOW)	1.0/1.0	20 µA/ −0.6 mA		
WE	Write Enable Input (Active LOW)	1.0/1.0	20 µA/ −0.6 mA		
CP Clock Input (Outputs Change on LOW-to-HIGH Transition)					
		1.0/2.0	20 μA/ −1.2 mA		
$Q_0 - Q_3$	TRI-STATE Outputs	150/40 (33.3)	-3 mA/24 mA (20 mA)		

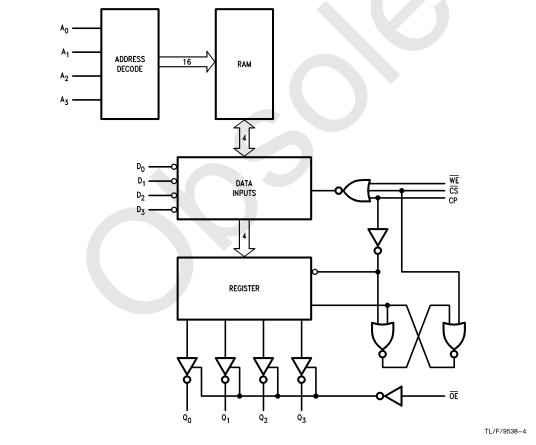
## **Functional Description**

Write Operation—When the three control inputs, Write Enable (WE), Chip Select ( $\overline{CS}$ ), and Clock (CP), are LOW the information on the data inputs ( $D_0-D_3$ ) is written into the memory location selected by the address inputs ( $A_0-A_3$ ). If the input data changes while  $\overline{WE}$ ,  $\overline{CS}$ , and CP are LOW, the contents of the selected memory location follow these changes, provided setup and hold time criteria are met.

**Read Operation**—Whenever  $\overline{CS}$  is LOW and CP goes from LOW-to-HIGH, the contents of the memory location selected by the address inputs (A<sub>0</sub>-A<sub>3</sub>) are edge-triggered into the Output Register.

The  $(\overline{OE})$  input controls the output buffers. When  $\overline{OE}$  is HIGH the four outputs  $(Q_0-Q_3)$  are in a high impedance or OFF state; when  $\overline{OE}$  is LOW, the outputs are determined by the state of the Output Register.

# **Block Diagram**



## Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	-65°C to +150°C
Ambient Temperature under Bias	-55°C to +125°C
Junction Temperature under Bias Plastic	−55°C to +175°C −55°C to +150°C
V <sub>CC</sub> Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to $+7.0V$
Input Current (Note 2)	-30 mA to $+5.0$ mA
Voltage Applied to Output in HIGH State (with $V_{CC} = 0V$ )	
Standard Output	-0.5V to V <sub>CC</sub>
TRI-STATE Output	-0.5V to +5.5V
Current Applied to Output	
in LOW/ Chata (Max)	tuine the reted (math)

#### Free Air Ambient Temperature Military

Conditions

**Recommended Operating** 

in LOW State (Max) twice the rated I<sub>OL</sub> (mA) Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

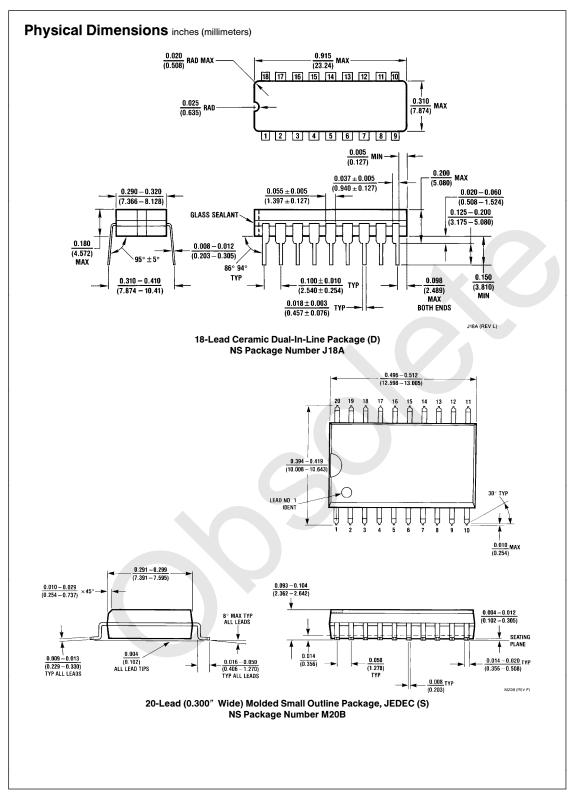
Note 2: Either voltage limit or current limit is sufficient to protect inputs.

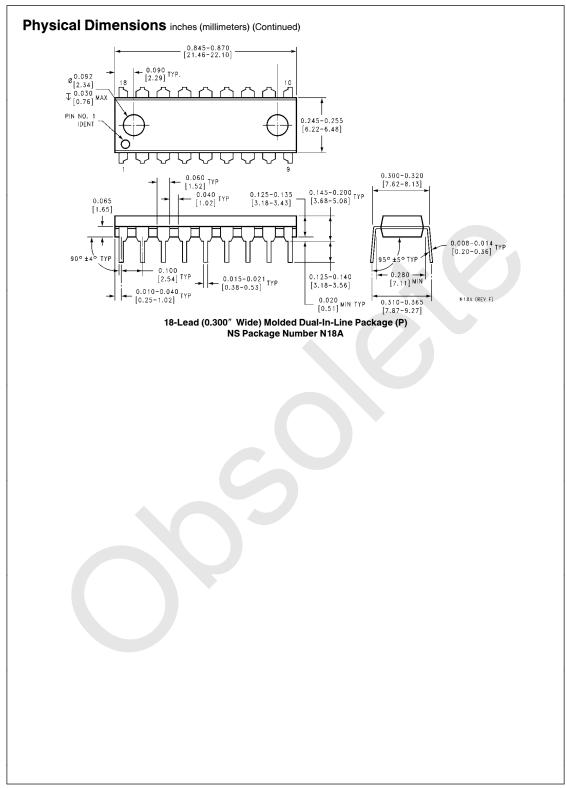
## **DC Electrical Characteristics**

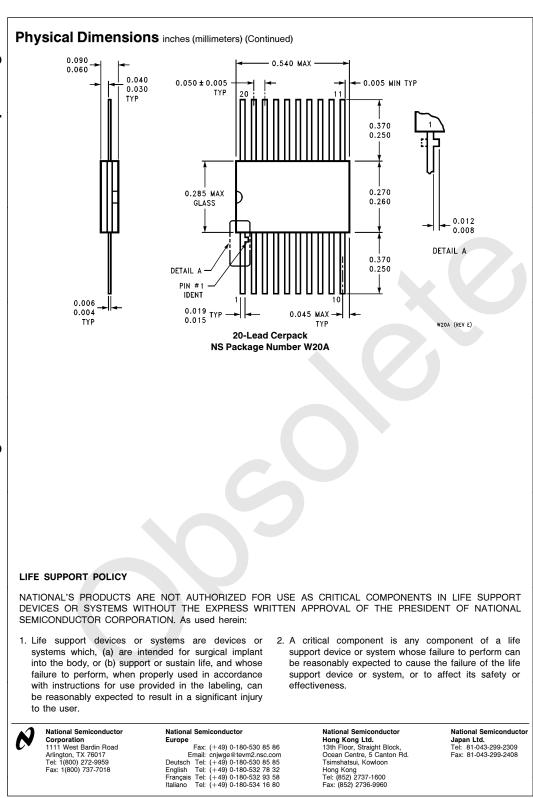
Symbol	Parameter - Input HIGH Voltage Input LOW Voltage Input Clamp Diode Voltage		54F/74F			Units	Vcc	Conditions	
Symbol			Min	Тур	Max	Units VCC		Conditions	
VIH			2.0			v		Recognized as a HIGH Signa	
VIL					0.8	v		Recognized as a LOW Signa	
V <sub>CD</sub>					-1.2	v	Min	$I_{IN} = -18 \text{ mA}$	
V <sub>OH</sub>	Output HIGH Voltage	54F 10% V <sub>CC</sub> 54F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub> 74F 5% V <sub>CC</sub>	2.5 2.4 2.5 2.4 2.7			v	Min	$\begin{split} I_{OH} &= -1 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ I_{OH} &= -1 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \end{split}$	
V <sub>OL</sub>	Output LOW Voltage	54F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub>			0.5 0.5	V	Min	$I_{OL} = 20 \text{ mA}$ $I_{OL} = 24 \text{ mA}$	
IIH	Input HIGH Current	54F 74F			20.0 5.0	μA	Max	$V_{IN} = 2.7V$	
I <sub>BVI</sub>	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	$V_{IN} = 7.0V$	
ICEX	Output HIGH Leakage Current	54F 74F	7		250 50	μΑ	Max	$V_{OUT} = V_{CC}$	
V <sub>ID</sub>	Input Leakage Test	74F	4.75			V	0.0	$I_{ID} = 1.9 \ \mu A$ All Other Pins Grounded	
I <sub>OD</sub>	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	V <sub>IOD</sub> = 150 mV All Other Pins Grounded	
Ι <sub>ΙL</sub>	Input LOW Current				-0.6 -1.2	mA	Max	$ \begin{array}{l} V_{\text{IN}} = 0.5 \text{V} \left( \text{A}_{\text{n}}, \text{D}_{\text{n}}, \overline{\text{OE}}, \overline{\text{WE}} \right) \\ V_{\text{IN}} = 0.5 \text{V} \left( \overline{\text{CS}}, \text{CP} \right) \end{array} $	
I <sub>OZH</sub>	Output Leakage Curre	ent			50	μΑ	Max	$V_{OUT} = 2.7V$	
I <sub>OZL</sub>	Output Leakage Curre	ent			-50	μΑ	Max	$V_{OUT} = 0.5V$	
I <sub>OS</sub>	Output Short-Circuit (	Current	-60		-150	mA	Max	$V_{OUT} = 0V$	
I <sub>ZZ</sub>	Bus Drainage Test				500	μA	0.0V	$V_{OUT} = 5.25V$	

Symbol	Paramete	r		54F/74F		Units	Vcc	Cor	nditions
Symbol Parameter		•	Min	Тур	Max	onito	•00	001	landonio
ICCH	Power Supply Current			47	70	mA	Max	V <sub>O</sub> =	= HIGH
I <sub>CCL</sub>	Power Supply Current	Power Supply Current		47	70	mA	Max	V <sub>O</sub> =	LOW
I <sub>CCZ</sub>	Power Supply Current			47	70	mA	Max	V <sub>O</sub> =	= HIGH Z
AC Ele	ctrical Characte	ristics							
		74F		5.0V $I_A, V_{CC} = MII$		74F T <sub>A</sub> , V <sub>CC</sub> = Com C <sub>L</sub> = 50 pF			
Symbol	Parameter	${f T_A}=\ +\ {f V_{CC}}=\ +\ {f C_L}=\ 5$	- 5.0V					Units	
		Min	Max	Min	Max	Mi	n	Мах	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay CP to Q	3.0 3.5	8.5 9.0	2.5 3.0	11.0 12.0	2.5 3.0		9.5 10.0	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Enable Time OE to Q	3.0 3.5	8.0 9.0	2.5 3.0	10.5 13.0	2.5		9.0 10.0	
t <sub>PHZ</sub>	Disable Time	2.5	6.5	2.0	8.5	2.0		7.5	ns
t <sub>PLZ</sub>	OE to Q	2.5	7.0	2.0	9.5	2.0	)	8.0	
AC Op	erating Require	ments							
			74F 54F			74F		_	
Symbol	Parameter		$\begin{array}{r} \textbf{T_A}=\ +\ \textbf{25^{\circ}C}\\ \textbf{V_{CC}}=\ +\ \textbf{5.0V} \end{array}$		$T_A, V_{CC} = M$		T <sub>A</sub> , V <sub>CC</sub> =	= Com Ur	Unit
		Min	Max	Mi	n	Max	Min	Мах	
		45.0					17.0		
t <sub>s</sub> (H) t <sub>s</sub> (L)	Setup Time, HIGH or LO A <sub>n</sub> to CP	N 15.0 15.0		23			17.0 17.0		
t <sub>h</sub> (H)	Hold Time, HIGH or LOW	/ 0		0			0		ns
t <sub>h</sub> (L)	A <sub>n</sub> to CP	0		0			0		
RITE MODE	E								
t <sub>s</sub> (H) t <sub>s</sub> (L)	Setup Time, HIGH or LOV A <sub>n</sub> to WE	W 0 0		0			0 0		
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold Time, HIGH or LOW A <sub>n</sub> to WE	/ 0 0			0		0		– ns
t <sub>s</sub> (H)	Setup Time, HIGH or LO	W 5.0		8.5		6.0			
t <sub>s</sub> (L) +. (⊔)		5.0		8.5		6.0		ns	
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold Time, HIGH or LOW D <sub>n</sub> to WE	0		2.			0 0		
t <sub>w</sub>	WE Pulse Width Required to Write			9.5		8.5		ns	
t <sub>w</sub>	CS Pulse Width Required to Write	7.5	7.5		9.5		8.5		ns
t <sub>w</sub>	CP Pulse Width Required to Write	7.5		9.	5		8.5		ns
Note: Milita	ary temperature range for t	his device is	-40°C to +8	35°C.		I			

	<u>74F</u>	410	s c	X	
Temperature Range Family 74F = Commercial 54F = Military			ĪĪ	L	Special Variations X = Devices shipped in 13" reels QB = Military grade device with
Device Type					environmental and burn-in processing
Package Code P = Plastic DIP S = Small Outline (SOIC) D = Ceramic DIP L = Package Leadless Chip Carrier					Temperature Range $C = Commercial (0^{\circ}C to + 70^{\circ}C)$ $M = Military (-55^{\circ}C to + 125^{\circ}C)$
					0







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